



Proposed List of Topics

1. Power scaling of High Power EUV sources (500-1000 W) to support extension of EUV Lithography beyond 3 nm node

Power scaling of plasma based EUV sources:

Power scaling and pulse shaping of CO₂ lasers

Power scaling and pulse shaping of pico second lasers (pre-pulse lasers)

Innovative tin fuel delivery systems, including mist targets and beyond

Debris mitigation systems (ionic and neutral debris)

New methods to improve conversion efficiency (CE) to predicted theoretical maximum value (Currently 8%)

Designs to improve collector lifetime including in-situ cleaning, active and passive debris mitigation

Technologies for filtering out-of-band (OOB) radiation at UV, IR and 10.6 μ wavelengths – including spectral purity filters, coatings and new multilayer (ML) collector designs

Development of new metrology techniques and tools to support power scaling

Development of new modelling tools to support power scaling (e.g., modelling of plasma sources and its interaction with source components) including analytical theory

Generation of precise fundamental atomic data to further improve modelling



13.5 nm FEL sources as alternate high-power EUV sources for EUVL scanners

Review of current FEL designs to support EUVL power requirements of 500- 1000 W

Innovative designs to address current challenges of FEL to support EUVL

Characteristics of FEL sources (brightness, power, source size, repetition frequency, techniques for altering coherence, foot print and cost of ownership)

Optics for FEL sources - challenges and innovative designs to address optics damage and lithography requirements

Economics of FEL sources – Cost of ownership (foot print, cost of source and cost of operation), time lines for technology readiness and R&D funding requirements

2. 13.5 nm laser produced plasma (LPP) sources of 250-500 W to support high volume manufacturing (HVM) scanners

Update on performance of high power EUV Sources (Sn LPP)

Approaches to increase uptime of current Sn LPP sources

Methods for power scaling to enable 250 -500 W sources with high (>90%) uptime

Refurbishment of multi-layer collectors for LPP sources

Metrology techniques to support increasing source performance and uptime

CO₂ laser amplifiers for 250-500 W sources

Modelling of sources, collectors and its components to improve source uptime, including analytical theory

Generation of more precise fundamental atomic data to support modelling

Synchrotron based metrology for HVM source collectors, filters, sensors and detectors

3. EUV Source for Metrology: Mask Defect Metrology, Pellicle Metrology and Metrology to support EUVL R&D and Manufacturing

Development status of sources to support EUV mask defect metrology (LPP, DPP, HHG etc.) and pellicle inspection

New source designs to support mask defect metrology and mask pellicle inspection tools

Source brightness requirements for EUV mask defect metrology tools



Limits of brightness for LPP and DPP mask defect metrology sources

Hybrid sources for mask defect metrology (e.g., LDP sources)

Spectral purity filters for metrology sources

Debris mitigation strategies for metrology sources

4. Broad-band (BB) EUV Sources for Advanced Metrology

Methods for generation of broad-band EUV light for advanced metrology applications

Requirements and Characterization of broad-band EUV sources

Applications of broad-band EUV sources

5. Lasers for supporting EUV and XUV Sources

Requirements, new designs, development and current status of lasers for following applications:

High power EUV Sources (CO₂ lasers)

Pre-pulse lasers for high power EUV Sources

LPP and DPP metrology sources

FEL sources (13.5 nm)

Broad-band EUV sources

Metrology Applications in advanced semiconductor manufacturing

6. XUV / Water window sources (~1 nm- 100 nm / 10 eV to 1 keV)

XUV Sources (plasma and non-plasma sources, incoherent and coherent sources) and its development status (power, brightness, wavelength region, repetition frequency, cost of ownership, lifetime, commercial readiness)

Collector optics for XUV sources (GI and ML)

Spectral purity filters and debris mitigation

Optics for XUV metrology (normal and grazing angle optics, filters, and gratings)



Detectors for XUV metrology

XUV metrology applications including water window microscopy, applications supporting EUV and

BEUV Lithography and microscopy

BEUV (6.x nm) sources and 6.x nm optics for Lithography Applications